Power MOSFET 24V, 6A, 23mΩ N-Channel Dual EFCP



http://onsemi.com

Features

- 2.5V drive
- Common-drain type
- 2KV ESD HBM

- Protection diode in
- Halogen free compliance

Applications

• Lithium-ion battery charging and discharging switch

Specifications

Absolute Maximum Ratings at Ta = 25°C

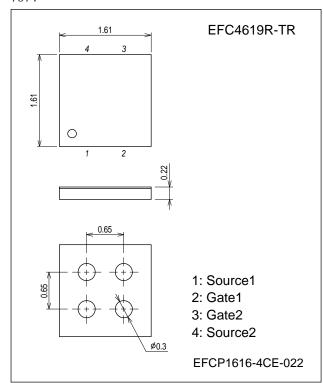
Parameter	Symbol	Conditions	Ratings	Unit
Source to Source Voltage	V _{SSS}		24	V
Gate to Source Voltage	V _{GSS}		±12	V
Source Current (DC)	IS		6	Α
Source Current (Pulse)	ISP	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit: mm (typ)

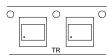
7074



Ordering & Package Information

Device	Package	Shipping	note
EFC4619R-TR	EFCP	5000 pcs. / reel	Pb-Free and Halogen-Free

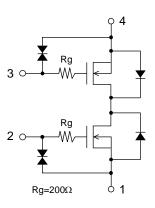
Packing Type: TR



Marking



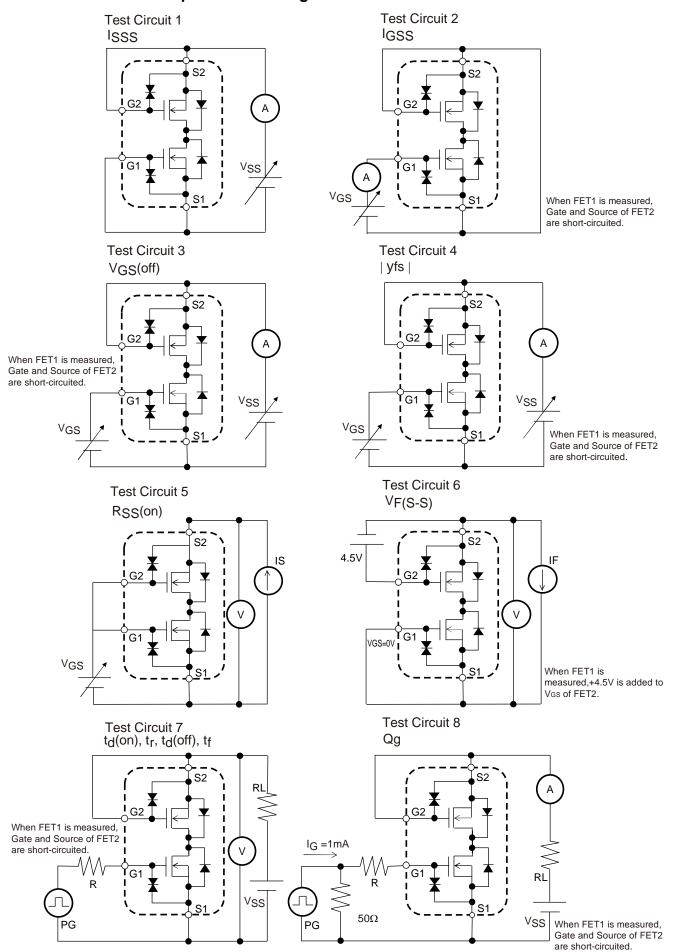
Electrical Connection

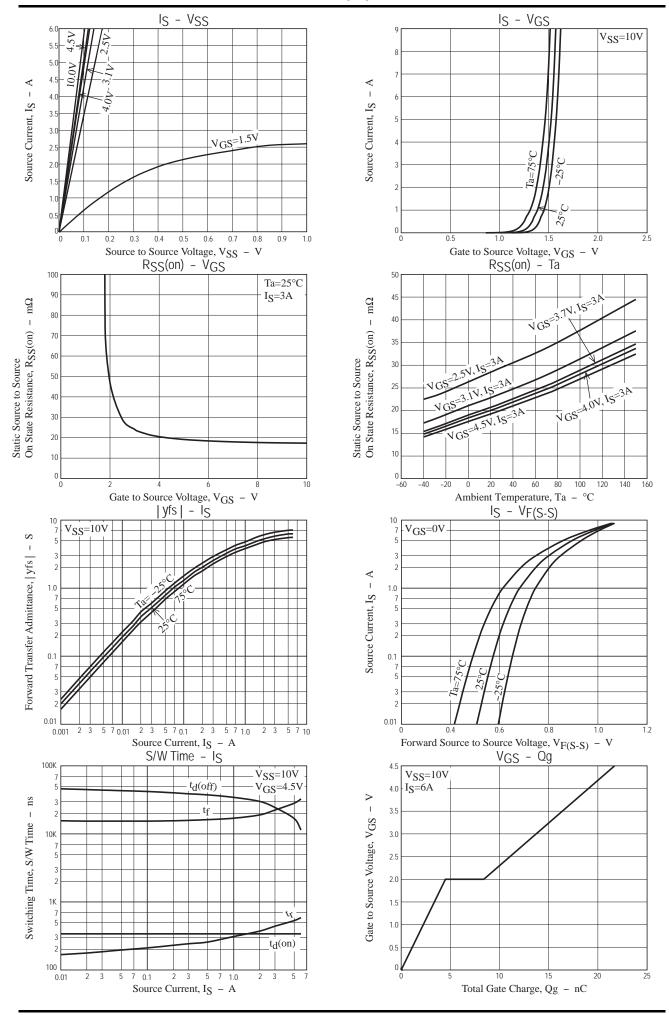


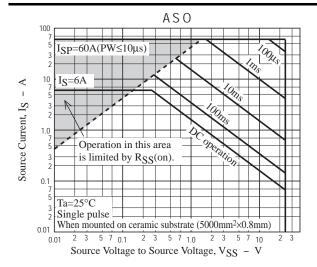
Electrical Characteristics at Ta = 25°C

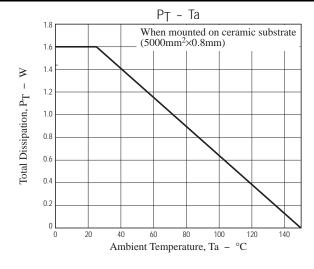
		Conditions		Ratings			
Parameter	Symbol			min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	I _S =1mA, V _{GS} =0V Test Circuit 1				V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μА
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1	μА
Cutoff Voltage	V _{GS} (off)	VSS=10V, IS=1mA	Test Circuit 3	0.5		1.3	V
Forward Transfer Admittance	yfs	V _{SS} =10V, I _S =3A	Test Circuit 4		5.8		S
	Rss(on)1	I _S =3A, V _{GS} =4.5V	Test Circuit 5	13.5	19.8	23	mΩ
	Rss(on)2	I _S =3A, V _G S=4.0V	Test Circuit 5	14	20.5	24	mΩ
Static Source to Source On-State Resistance	Rss(on)3	I _S =3A, V _{GS} =3.7V	Test Circuit 5	14.5	21	25.5	mΩ
esistance	Rss(on)4	I _S =3A, V _{GS} =3.1V	Test Circuit 5	14.9	23	30	mΩ
	Rss(on)5	I _S =3A, V _{GS} =2.5V	Test Circuit 5	18.5	27	35	mΩ
Turn-ON Delay Time	t _d (on)				340		ns
Rise Time	t _r				440		ns
Turn-OFF Delay Time	t _d (off)	VSS=10V, VGS=4.5V, IS=3A Test Circuit 7			24400		ns
Fall Time	tf				22400		ns
Total Gate Charge Qg		V _{SS} =10V, V _{GS} =4.5V, I _S		21.7		nC	
Forward Source to Source Voltage	V _F (S-S)	IS=3A, VGS=0V	Test Circuit 6		0.8	1.2	V

Test circuits are example of measuring FET1 side







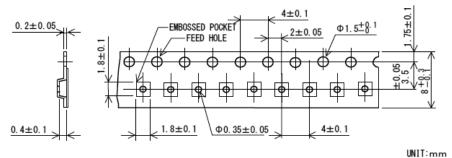


Taping Specification

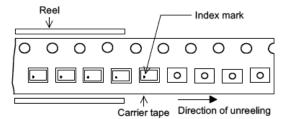
EFC4619R-TR

1. Taping Configuration

1- 1 .Carrier Tape Size (unit:mm)

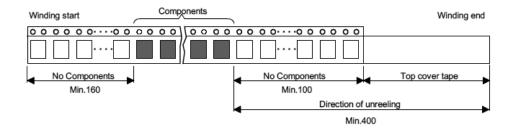


1-2. Device Placement Direction



Packing type···· TR

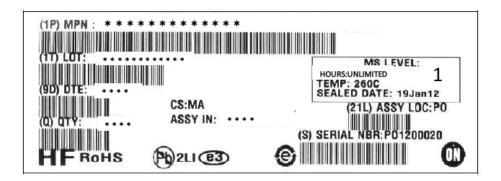
1-3 .Leader portion and Trailer portion (unit:mm)



Packing Format

Carrier Tape code	Package code	Maximum Number of devices contained. (pcs.)		Packing Format		
		Reel	Inner box		Inner box BOX(C-1)	
1818X04	EFCP1616-4CE-022	5,000	25,000		5reels contained. Dimensions:mm 183×72×185	

MPN Label



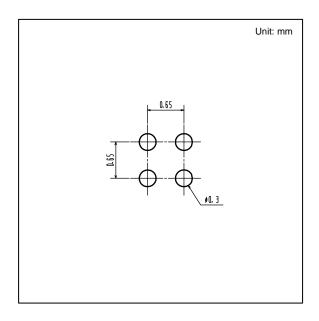
Packing Method



Outline Drawing

EFC4619R-TR

Land Pattern Example



Note on usage: Since the EFC4619R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equa

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: EFC4619R-TR